

Green Products

#### Technical Data Data Sheet N0901, Rev. A

# SBRF1060CTL SCHOTTKY RECTIFIER

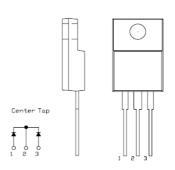
#### **Applications:**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

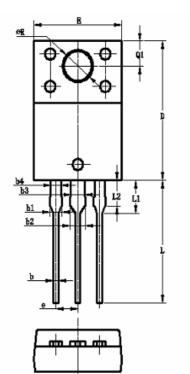
#### Features:

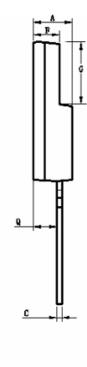
- 150°C TJ operation
- Center tap configuration
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

#### **Mechanical Dimensions: In mm**



#### **OUTLINE DRAWING**





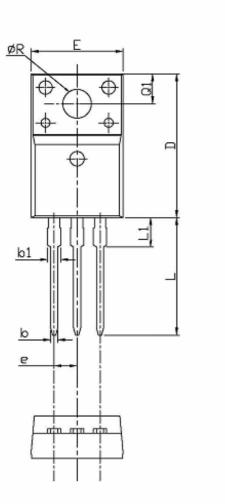
	OPTION 1(CJ)		001101	N 2(HD)	
Dim	Min	Max	Min	Max	
Α	4.4	4.6	4.30	4.70	
b	0.61	ΥP	0.50	0.75	
b1	1.31	ΥP	1.30	1.40	
b2	1.71	ΥP	1.70	1.80	
b3	1.61	ΥP	1.50	1.75	
b4	1.21	1.2TYP		1.35	
С	0.60TYP		0.50	0.75	
D	14.8	15.1	14.80	15.20	
Е	10.06	10.26	9.96	10.36	
е	2.55TYP		2.54TYP		
F	2.9	3.1	2.80	3.20	
G	6.5	6.9	6.50	6.90	
L	12.7	13.7	12.8	13.2	
L1	3.4	3.8	3.60	4.00	
L2	2.6	3.0	-	-	
Q	2.5	2.9	2.50	2.90	
Q1	2.5	2.5 2.9		2.70REF	
ØR	3.5F	3.5REF		REF	

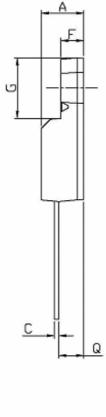
Weiqi Street, Airport Development Zone, Jiangning District, Nanjing, China 211113 (86) 25-87123907 •
FAX (86) 25-87123900 • World Wide Web Site - http://www.sangdest.com.cn • E-Mail Address - sales@ sangdest.com.cn •



Green Products

Technical Data Data Sheet N0901, Rev. A

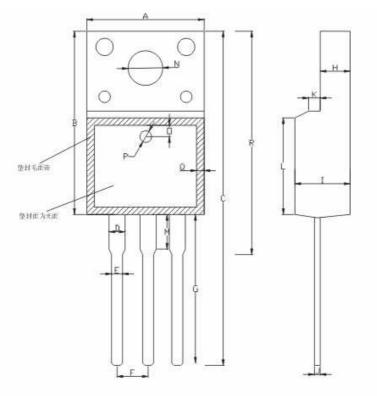




	OPTIC	ON 3	OPTION 4	
Dim	Min	Max	Min	Мах
Α	4.53	4.93	4.50	4.90
b	0.71	0.91	0.70	0.90
b1	1.15	1.39	1.33	1.47
С	0.36	0.53	0.45	0.60
D	15.67	16.07	15.67	16.07
Е	9.96	10.36	9.96	10.36
е	2.54	ГҮР	2.54 BSC	
F	2.34	2.76	2.34	2.74
G	6.50	6.90	6.48	6.88
L	12.37	12.77	12.78	13.18
L1	2.23	2.63	3.03	3.43
Q	2.56	2.96	2.56	2.96
Q1	3.10	3.50	3.10	3.50
ØR	2.98	3.38	3.08	3.28



Technical Data Data Sheet N0901, Rev. A **Green Products** 



A:10.20	$\pm 0.50$	B:15.90	$\pm 0.50$	C:29.00	$\pm 1.00$	D:1.24	$\pm 0.10$
E:0.80	$\pm 0.10$	F:2.54	$\pm 0.10$	G:13.10	$\pm 1,0$	H:2.55	$\pm 0.05$
I:4.70	$\pm 0.05$	J:0.50	$\pm 0.05$	K:1.20	$\pm 0.20$	L:8.00	$\pm 0.50$
M:3.00	$\pm 0.50$	N:3.20	$\pm 0.20$	O:1,25	$\pm 0.05$	P:1.5	$\pm 0.05$
Q:1.0	±0.20	R:19.2	$\pm 1.0$				

## **OPTION 5 (SR)**

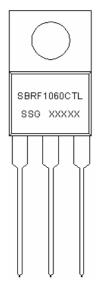
ITO-220AB



#### Technical Data Data Sheet N0901, Rev. A

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### Marking Diagram:



Where XXXXX is YYWWL

SBR	= Device Type
F	= Package type
10	= Forward Current (10A)
60	= Reverse Voltage (60V)
CTL	= Configuration
SSG	= SSG
YY	= Year
WW	= Week
L	= Lot Number

#### Cautions: Molding resin Epoxy resin UL:94V-0

## **Ordering Information:**

Device	Package	Shipping
SBRF1060CTL	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

#### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	60	V
Max. Average Forward	I <sub>F(AV)</sub>	50% duty cycle @T <sub>C</sub> =133°C, rectangular wave form	10(Per leg) 20(Per device)	A
Max. Peak One Cycle Non- Repetitive Surge Current (per leg)	I <sub>FSM</sub>	8.3 ms, half Sine pulse	125	А



#### Technical Data Data Sheet N0901, Rev. A

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## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
	V <sub>F1</sub>	@ 3 A, Pulse, T <sub>J</sub> = 25 °C	0.65	V
Max. Forward Voltage Drop		@ 5 A, Pulse, T <sub>J</sub> = 25 °C	0.75	
(per leg)*	V <sub>F2</sub>	@ 3 A, Pulse, T <sub>J</sub> = 125 °C	0.55	V
		@ 5 A, Pulse, T <sub>J</sub> = 125 °C	0.65	
Max. Reverse Current at DC	I <sub>R1</sub>	$@V_{R} = rated V_{R}$	1.0	mA
condition (per leg)		T <sub>J</sub> = 25 °C		
Max. Reverse Current (per	I <sub>R2</sub>	$@V_{R} = rated V_{R}$	15	mA
leg)*		T <sub>J</sub> = 125 °C		
Max. Junction Capacitance	Ст	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	220	pF
(per leg)		f <sub>SIG</sub> = 1MHz		
Typical Series Inductance	Ls	Measured lead to lead 5 mm from	8.0	nH
(per leg)		package body		
Max. Voltage Rate of Change	dv/dt	-	10,000	V/µs
RSM Isolation Voltage	V <sub>ISO</sub>	Clip mounting, the epoxy body	4500	V
(t = 1.0 second, R. H. < =30%,		away from the heatsink edge by		
T <sub>A</sub> = 25 °C)		more than 0.110" along the lead		
		direction.		
		Clip mounting, the epoxy body is	3500	
		inside the heatsink.		
		Screw mounting, the epoxy body	1500	
		is inside the heatsink.		

\* Pulse Width < 300µs, Duty Cycle <2%

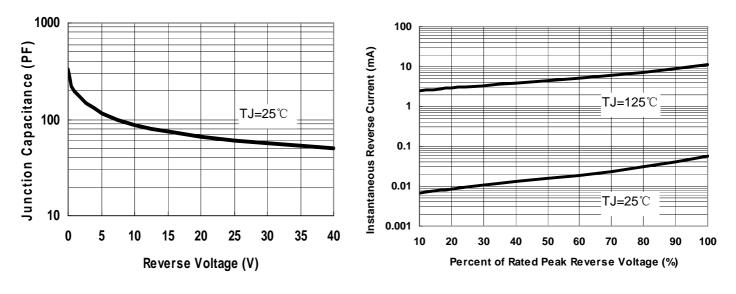
# **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature Range	TJ	-	-55 to +150	°C
Storage Temperature Range	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case (per leg)	R <sub>θJC</sub>	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style		ITO-220AB		



**Green Products** 

Technical Data Data Sheet N0901, Rev. A





**Fig.2-Typical Reverse Characteristics** 

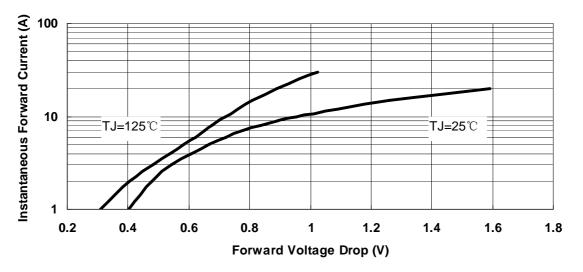


Fig.3-Typical Instantaneous Forward Voltage Characteristics



#### Technical Data Data Sheet N0901, Rev. A

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